20 STERN AVE. SPRINGFIELD. NEW JERSEY 07081 U.S.A.

CONTROLLED AVALANCHE

Silicon Rectifier

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1N4529-30

Up to 1200V 35A Avg.

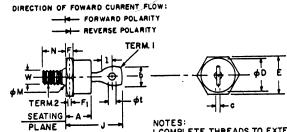
MAXIMUM ALLOWABLE RATINGS Repetitive & Working Peak Reverse Voltage* MINIMUM Avalanche Breakdown MAXIMUM Avalanche Breakdown Full-Load Reverse Current Type VRM(rep), VRM(wkg) Voltage, BVR, (5 mA test Voltage, BV_R, (5 mA test (full-cycle avg., 115°C Tc, $T_1 = -65^{\circ}C$ to $+175^{\circ}C$ current at T_J = 25°C) current at T₁ = 25°C) 1ϕ), $I_{R(AV)}$ (Note: 1) Volts** Volts Milliamperes** Volts 1N4529,R 1000 1250 1550 1N4530,R 1200

1930 1500 Average Forward Current, I_0 ($T_c = +115$ °C, single phase) 35 Amperes** Peak One-Cycle Surge Current (non-repetitive), I_{FM} (surge) 500 Amperes** Minimum I²t Rating (see Curve 6). Soo Amperes Reverse Power Surge (non-repetitive, 10 μ sec., square wave) $T_J = +25^{\circ}C$. 12 Kilowatts $T_J = +175^{\circ}C$. 4.5 Kilowatts Average DC Reverse Power in Breakdown Region $(-65^{\circ}\text{C} \le T_{\text{C}} \le +115^{\circ}\text{C})$ (Note: 2) 20 Watts** Peak Reverse Power in Breakdown Region (repetitive) (Note: 2) 100 Watts Forward Peak Voltage Drop, V_{FM} ($T_{\text{C}} = +115^{\circ}\text{C}$, $I_{\text{O}} = 12$ ampere avg.) 1.4 Volts** Thermal Resistance, $\theta_{\text{J.C.}}$ 1.0°C/Watt Operating Junction Temperature, $T_{\text{J.}}$ 1.0°C/Watt Storage Temperature, $T_{\text{Alg.}}$ 1.0°C to $+175^{\circ}\text{C}$ ** Storage Temperature, $T_{\text{Alg.}}$ 20 Watts** 35 Kg-cm *Maximum voltages apply with a heatsink thermal resistance of 8°C/watt, or less, at maximum rated junction temperature.
**Indicates values included in JEDEC Type Number Registration.

NOTES:
(1) VRM(rep) applies for a conventional AC to DC conversion application. VRM(rep) and VRM(wkg) can be considered unlimited providing that the additional reverse power generation is taken into account by allowing for its influence on the forward current rating. Considerations similar to voltage regulator diode applications would apply.
(2) These ratings assume no forward power dissipation. In applications requiring both forward and reverse average power dissipation, reduce case temperature as determined from the maximum case temperature versus average forward current curve by 2.0°C for every watt of average reverse power dissipation.

OUTLINE DRAWING

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
Α		.450		11.43	
b		.375		9.53	2
С		.080		2.03	
φD		.667		16.94	
Ε	.667	.687	16.94	17.45	
F	.115	.200	2.92	5.08	
F ₁	.060		1.52		
J		1.000		25.40	
1	.156		3.96		4
фМ	.220	.249	5.59	6.32	ı
N	.422	.453	10.72	11.51	
φt	.140	.175	3.56	4.45	
W					1,3



ILCOMPLETE THREADS TO EXTEND TO WITHIN 2-1/2
THREADS OF SEATING PLANE.

2. ANGULAR ORIENTATION OF TERMINAL IS UNDEFINED.

2. ANOUGH ON THE NIGHT OF THE NIGHT OF PLATED THREADS SHALL BE BASIC PITCH DIAMETER (.2268", 5.74 MM) REF (SCREW THREAD STANDARDS FOR FEDERAL SERVICES 1957) HANDBOOK H28 1957 PI.

4. MINIMUM FLAT.

EIA-NEMA STANDARD OUTLINE, NEMA SK-51- EIA RS-241. INSULATING HARDWARE IS AVAILABLE UPON REQUEST.

COMPLIES WITH EIA REGISTERED OUTLINE DO-5



Quality Semi-Conductors